

- 2:30 D-61 **GRAZING-INCIDENT X-RAY DIFFRACTION ANALYSES OF NOVEL MAGNETIC THIN FILMS—Invited**  
K. Inaba, Y. Ito, K. Omote, H. Toraya, *Rigaku Corporation, Tokyo, Japan*
- 3:00 D-12 **ULTRA-FAST SIMULTANEOUS FITTING OF SEVERAL BRAGG REFLECTIONS FROM AIAs/GaAs SUPERLATTICES USING METHOD OF EIGENWAVES**  
A. Ulyanenkov, R. Eisenhower, I. Feranchuk, H. Guérault, H. Röss, *Bruker AXS, Karlsruhe, Germany*
- 3:20 **Break**
- 3:50 D-5 **THE DIRECT DETERMINATION OF X-RAY DIFFRACTION DATA FROM SPECIFIC DEPTHS**  
A. Broadhurst, K.D. Rogers, D.W. Lane, T.W. Lowe, *Cranfield Univeristy, Swindon, UK*
- 4:10 D-70 **“BaF<sub>2</sub> PROCESS”: PHASE EVOLUTION OF Ba<sub>2</sub>YCu<sub>3</sub>O<sub>6+x</sub> FILMS**  
W. Wong-Ng, I. Levin, M.D. Vaudin, L.P. Cook, *National Institute of Standards & Technology, Gaithersburg, MD*  
R. Feenstra, *Oak Ridge National Laboratory, Oak Ridge, TN*
- 4:30 D-89 **IN-SITU HTXRD CHARACTERIZATION FOR THIN FILMS**  
E.A. Payzant, S.A. Speakman, *Oak Ridge National Laboratory, Oak Ridge, TN*

## XRD

Wednesday p.m.

Twilight

### Session D-1 Small Angle Scattering

Organized by: N.S. MURTHY, University of Vermont, Burlington, VT  
J.D. LONDONO, DuPont Company, Wilmington, DE

- 2:00 D-108 **IN SITU STUDIES OF NANO-PARTICLE GROWTH IN FLAMES—Invited**  
G. Beaucage, N. Agashe, *University of Cincinnati, Cincinnati, OH*  
H.K. Kammler, S.E. Pratsinis, *Institute of Process Engineering, ETH Zentrum, Zurich, Switzerland*  
J. Ilavsky, P. Jemian, *UNICAT, Advanced Photon Source, Argonne, IL*  
T. Narayanan, *ID02, European Synchrotron Research Facility, Grenoble, France*  
D. Londono, *Dupont Experimental Station, Wilmington, DE*
- 2:30 D-106 **IN-SITU STRUCTURAL STUDIES OF SEMICRYSTALLINE POLYMER BLENDS USING SYNCHROTRON RADIATION—Invited**  
P. Thiyagarajan, S. Seifert, *Argonne National Laboratory, Argonne, IL*  
M. Kipper, B. Narasimhan, *Iowa State University, Ames, IA*
- 3:00 D-91 **LOOKING AT SMALL HOLES: CROSS-VALIDATION OF SAXS- AND BET-POROSIMETRY**  
P. Laggner, *Austrian Academy of Sciences, Graz, Austria and Hecus X-ray Systems GmbH, Graz, Austria*
- 3:20 **Break**
- 3:40 D-101 **FROM LAB TO FAB: THE DEVELOPMENT AND DEPLOYMENT OF NEW METROLOGY TECHNOLOGY FOR THE GLOBAL SEMICONDUCTOR INDUSTRY—Invited**  
B. Landes, B. Kern, J. Niu, C. Mohler, J. Hahnfeld, D. Yontz, K. Ender, C. Silvis, R. Strittmatter, L. Moore, T. Stokich, D. King, *Dow Chemical Co., Midland, MI*  
J. Quintana, S. Weigand, *Northwestern University, Chicago, IL*